BUK545-60H

GENERAL DESCRIPTION

N-channel enhancement mode logic level field-effect power transistor in a plastic full-pack envelope. The device is intended for use in Automotive applications, Switched Mode Power Supplies (SMPS), motor control, welding, DC/DC and AC/DC converters, and in general purpose switching applications.

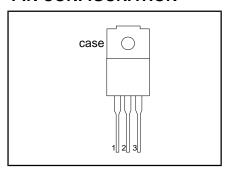
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V _{DS} I _D Ptot T _j R _{DS(ON)}	Drain-source voltage Drain current (DC) Total power dissipation Junction temperature Drain-source on-state resistance; V _{GS} = 5 V	60 21 30 150 38	V A W °C mΩ

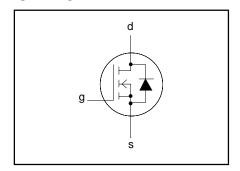
PINNING - SOT186

PIN	DESCRIPTION
1	gate
2	drain
3	source
case	isolated

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	Drain-source voltage	-	-	60	V
V_{DGR}	Drain-gate voltage	$R_{GS} = 20 \text{ k}\Omega$	-	60	V
±V _{GS}	Gate-source voltage	-	-	15	V
±V _{GSM}	Non-repetitive gate-source voltage	$t_p \le 50 \ \mu s$	-	20	V
I _D	Drain current (DC)	$T_{hs} = 25 ^{\circ}C$	-	21	Α
I _D	Drain current (DC)	T _{hs} = 100 °C	-	13.5	Α
I _{DM}	Drain current (pulse peak value)	$T_{hs} = 25 ^{\circ}C$	-	82	Α
P _{tot}	Total power dissipation	$T_{hs}^{ns} = 25 ^{\circ}C$	-	30	W
T _{stg}	Storage temperature	-	- 55	150	°C
T_{j}	Junction Temperature	-	-	150	°C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th j-hs}	Thermal resistance junction to heatsink Thermal resistance junction to	With heatsink compound	- 55	4.17	K/W K/W
R _{th j-a}	ambient		33	-	17/ 7/

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STATIC CHARACTERISTICS

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)DSS}$	Drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.25 \text{ mA}$	60	1	1	٧
V _{GS(TO)} I _{DSS} I _{DSS} I _{GSS} R _{DS(ON)}	Gate threshold voltage	$\begin{aligned} &V_{DS} = V_{GS}; I_D = 1 \text{ mA} \\ &V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C} \\ &V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 125 \text{ °C} \\ &V_{GS} = \pm 15 \text{ V}; V_{DS} = 0 \text{ V} \\ &V_{GS} = 5 \text{ V}; \\ &I_D = 20 \text{ A} \end{aligned}$	1.0 - - -	1.5 1 0.1 10 25	2.0 10 1.0 100 38	V μA mA nA mΩ

DYNAMIC CHARACTERISTICS

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
g fs	Forward transconductance	$V_{DS} = 25 \text{ V}; I_{D} = 20 \text{ A}$	11	20	1	S
C _{iss} C _{oss} C _{rss}	Input capacitance Output capacitance Feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 25 \text{ V}; f = 1 \text{ MHz}$		1200 470 180	1750 600 275	pF pF pF
$t_{d \text{ on}}$ t_{r} $t_{d \text{ off}}$ t_{f}	Turn-on delay time Turn-on rise time Turn-off delay time Turn-off fall time	$V_{DD} = 30 \text{ V}; I_D = 3 \text{ A}; \ V_{GS} = 5 \text{ V}; R_{GS} = 50 \Omega; \ R_{gen} = 50 \Omega$		25 120 160 110	40 150 220 145	ns ns ns ns
L _d	Internal drain inductance Internal source inductance	Measured from drain lead 6 mm from package to centre of die Measured from source lead 6 mm from package to source bond pad	-	4.5 7.5	-	nH nH

ISOLATION LIMITING VALUE & CHARACTERISTIC

 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	Repetitive peak voltage from all three terminals to external heatsink	R.H. ≤ 65% ; clean and dustfree	1		1500	V
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	-	12	-	pF

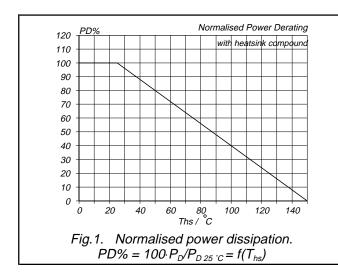
REVERSE DIODE LIMITING VALUES AND CHARACTERISTICS

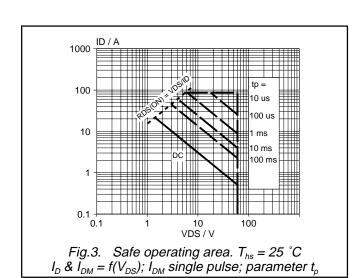
 T_{hs} = 25 °C unless otherwise specified

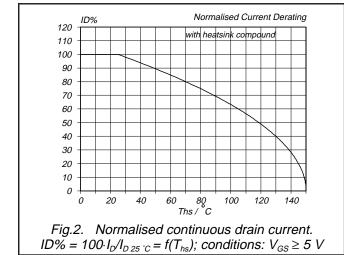
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{DR}	Continuous reverse drain current	-	-	-	21	Α
$I_{DRM} \ V_{SD}$	Pulsed reverse drain current Diode forward voltage	$I_F = 21 \text{ A}$; $V_{GS} = 0 \text{ V}$		- 0.9	84 2.0	A V
t _{rr} Q _{rr}	Reverse recovery time Reverse recovery charge	$I_F = 21 \text{ A}; -dI_F/dt = 100 \text{ A/}\mu\text{s};$ $V_{GS} = 0 \text{ V}; V_R = 30 \text{ V}$	-	60 0.25		ns μC

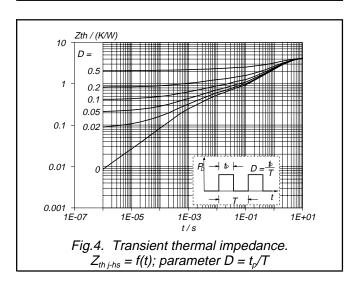
AVALANCHE LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
W _{DSS}		$I_D = 41 \text{ A ; } V_{DD} \le 25 \text{ V ; } T_{hs} = 25 \text{ °C}$ $V_{GS} = 5 \text{ V ; } R_{GS} = 50 \Omega$	-	1	90	mJ

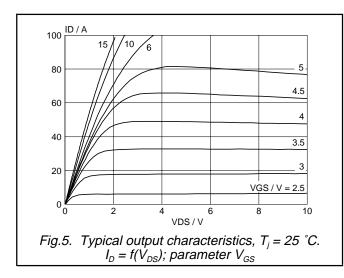


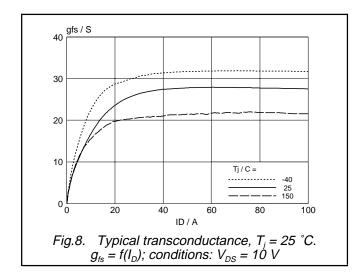


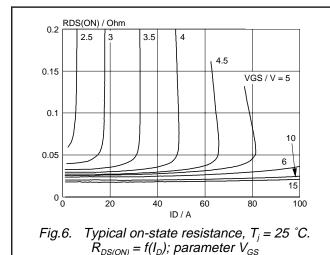


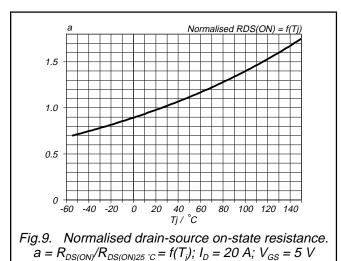


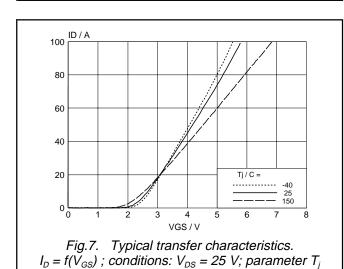
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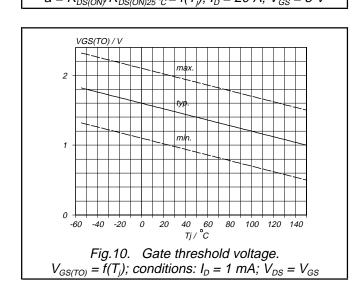




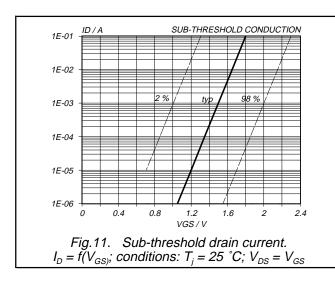


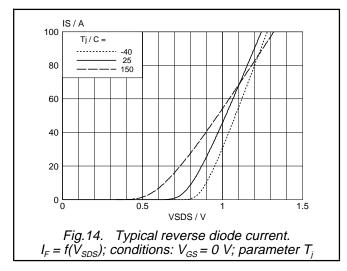


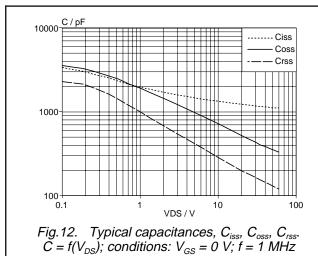


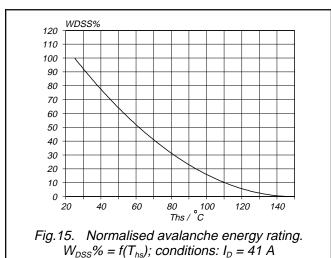


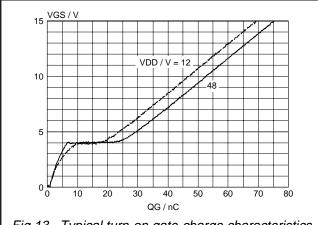
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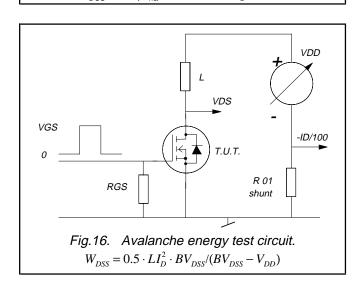
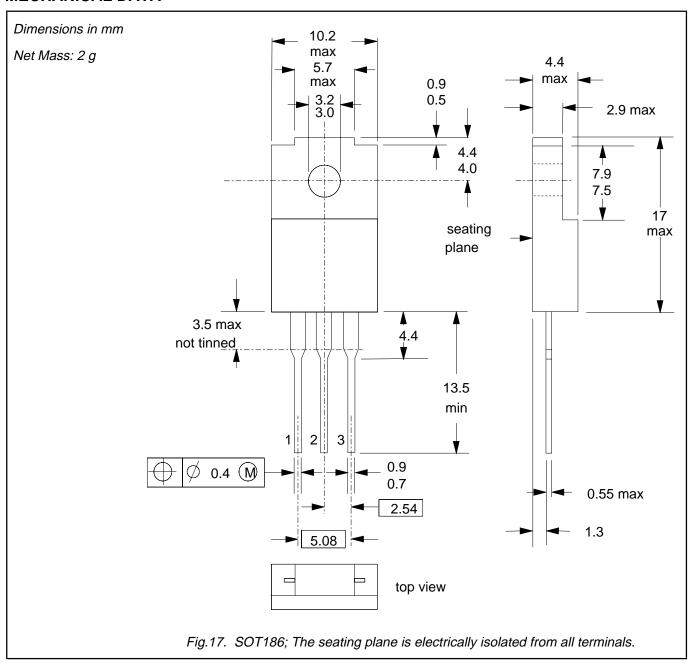


Fig.13. Typical turn-on gate-charge characteristics. $V_{GS} = f(Q_G)$; conditions: $I_D = 41$ A; parameter V_{DS}

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MECHANICAL DATA



Notes

- 1. Observe the general handling precautions for electrostatic-discharge sensitive devices (ESDs) to prevent damage to MOS gate oxide.
- 2. Refer to mounting instructions for F-pack envelopes.
- 3. Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
1 ''4'					

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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